

# KTC3265 TRANSISTOR (NPN)

### **FEATURES**

- High DC current gain
- Complementary to KTA1298

# 1.BASE 2.COLLECTOR 3.EMITTER SOT-23-3

# MAXIMUM RATINGS ( $T_a$ =25 $^{\circ}$ C unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	35	V
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current	800	mA
Pc	Collector Power Dissipation	200	mW
R <sub>OJA</sub>	Thermal Resistance From Junction To Ambient	625	°C/W
T <sub>J</sub> ,T <sub>stg</sub>	Operation Junction and Storage Temperature Range	-55~+150	℃

# ELECTRICAL CHARACTERISTICS ( $T_a$ =25 $^{\circ}$ C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = 100μΑ, I <sub>E</sub> =0	35			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = 10mA, I <sub>B</sub> =0	30			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =100μΑ, I <sub>C</sub> =0	5			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =30 V, I <sub>E</sub> =0			0.1	μΑ
Collector cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =5 V, I <sub>C</sub> =0			0.1	μΑ
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> =1V, I <sub>C</sub> = 100mA	100		320	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> =500mA, I <sub>B</sub> =20mA			0.5	V
base-emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> =1V,I <sub>C</sub> =10mA	0.5		0.8	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA f=100MHz		120		MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V,I <sub>E</sub> =0,f=1MH <sub>Z</sub>		13		pF

### CLASSIFICATION OF hFE

Rank	0	Y			
Range	100-200	160-320			
Marking	EO	EY			



